TOSHIBA

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

2SC3072

Strobe Flash Applications Medium Power Amplifier Applications

- High DC current gain
 - : $h_{FE} = 140$ to 450 ($V_{CE} = 2$ V, $I_C = 0.5$ A)
- hFE = 70 (min) (VCE = 2 V, IC = 4 A)
 Low collector saturation voltage

Maximum Ratings (Ta = 25°C)

- V_{CE} (sat) = 1.0 V (max) (IC = 4 A, IB = 0.1 A)
- High power dissipation : $P_C = 10 W (T_c = 25^{\circ}C), P_C = 1.0 W (T_a = 25^{\circ}C)$

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	50	V	
Collector-emitter voltage		V _{CES}	40	V	
		V _{CEO}	20		
Emitter-base voltage		V _{EBO}	8	V	
Collector current	DC	Ι _C	5	A	
	Pulse (Note 1)	I _{CP}	8		
Base current		Ι _Β	0.5	А	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	FC	10		
Junction temperature		Тj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note 1: Pulse test: Pulse width = 10 ms (max), duty cycle = 30% (max)



Weight: 0.36 g (typ.)



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Unit: mm

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 40 V, I _E = 0	_	_	100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 8 V, I _C = 0		_	100	nA
Collector-emitter breakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	20	—	-	V
DC current gain	h _{FE (1)} (Note 2)	V _{CE} = 2 V, I _C = 0.5 A	140	_	450	
	h _{FE (2)}	V _{CE} = 2 V, I _C = 4 A	70	—	_	
Collector emitter saturation voltage	V _{CE (sat)}	I _C = 4 A, I _B = 0.1 A	_	—	1.0	V
Base-emitter voltage	V _{BE}	V _{CE} = 2 V, I _C = 4 A	_	—	1.5	V
Transition frequency	f _T	V _{CE} = 2 V, I _C = 0.5 A	_	100	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	-	40	_	pF

Note 2: h_{FE (1)} classification A: 140 to 240, B: 200 to 330, C: 300 to 450

Marking



Explanation of Lot No.



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1.6

2.0





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